

**12 A Three-quadrant triacs high commutation** Rev. 01 — 12 April 2007

**Product data sheet** 

# 1. Product profile

## 1.1 General description

Passivated, new generation, high commutation triacs in a SOT404 plastic single-ended surface-mountable package

### 1.2 Features

Very high commutation performance
 High immunity to dV/dt
 maximized at each gate sensitivity

## **1.3 Applications**

- High power motor control e.g. washing
   Non-linear rectifier-fed motor loads machines, vacuum cleaners
   Refrigeration and air conditioning
   Electronic thermostats
- Refrigeration and air conditioning compressors

## 1.4 Quick reference data

- V<sub>DRM</sub> ≤ 600 V (BTA312B-600B/C)
- V<sub>DRM</sub> ≤ 800 V (BTA312B-800B/C)
- I<sub>TSM</sub> ≤ 95 A (t = 20 ms)
- I<sub>GT</sub>  $\leq$  50 mA (BTA312B series B)
- I<sub>GT</sub>  $\leq$  35 mA (BTA312B series C)
- I<sub>T(RMS)</sub> ≤ 12 A

# 2. Pinning information

Table 1.	Pinning		
Pin	Description	Simplified outline	Symbol
1	main terminal 1 (T1)		N 1
2	main terminal 2 (T2)	mb	T2-T1
3	gate (G)		sym051
mb	mounting base; main terminal 2 (T2)	/ i /	

SOT404 (D2PAK)



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## 3. Ordering information

Type number	Package					
	Name	Description	Version			
BTA312B-600B	D2PAK	plastic single-ended surface-mounted package (D2PAK); 3-leads (one lead				
BTA312B-600C		cropped)				
BTA312B-800B						
BTA312B-800C						

# 4. Limiting values

### Table 3.Limiting values

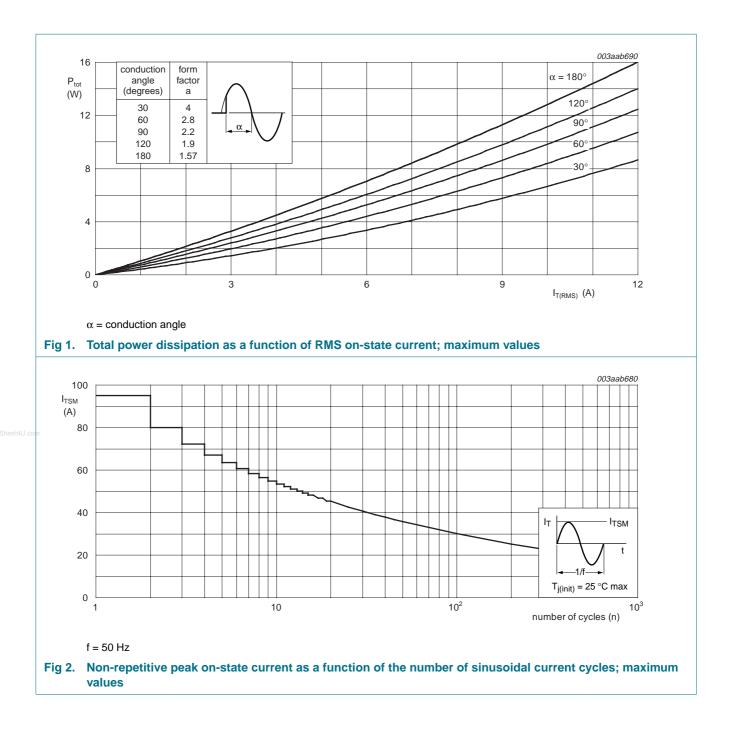
In accordance with the Absolute Maximum Rating System (IEC 60134).

• • •		A 11/1			
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage	BTA312B-600B; BTA312B-600C	<u>[1]</u> _	600	V
		BTA312B-800B; BTA312B-800C	-	800	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; $T_{mb} \le 101 \text{ °C}$ ; see Figure 4 and 5	-	12	А
I <sub>TSM</sub>	non-repetitive peak on-state current	full sine wave; $T_j = 25 \text{ °C prior to}$ surge; see <u>Figure 2</u> and <u>3</u>			
		t = 20 ms	-	95	А
		t = 16.7 ms	-	105	А
l <sup>2</sup> t	l <sup>2</sup> t for fusing	t = 10 ms	-	45	A <sup>2</sup> s
dl <sub>T</sub> /dt	rate of rise of on-state current	$I_{TM} = 20 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu \text{s}$	-	100	A/µs
I <sub>GM</sub>	peak gate current		-	2	А
P <sub>GM</sub>	peak gate power		-	5	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	-	0.5	W
T <sub>stg</sub>	storage temperature		-40	+150	°C
Ti	junction temperature		-	125	°C

[1] Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 A/µs.

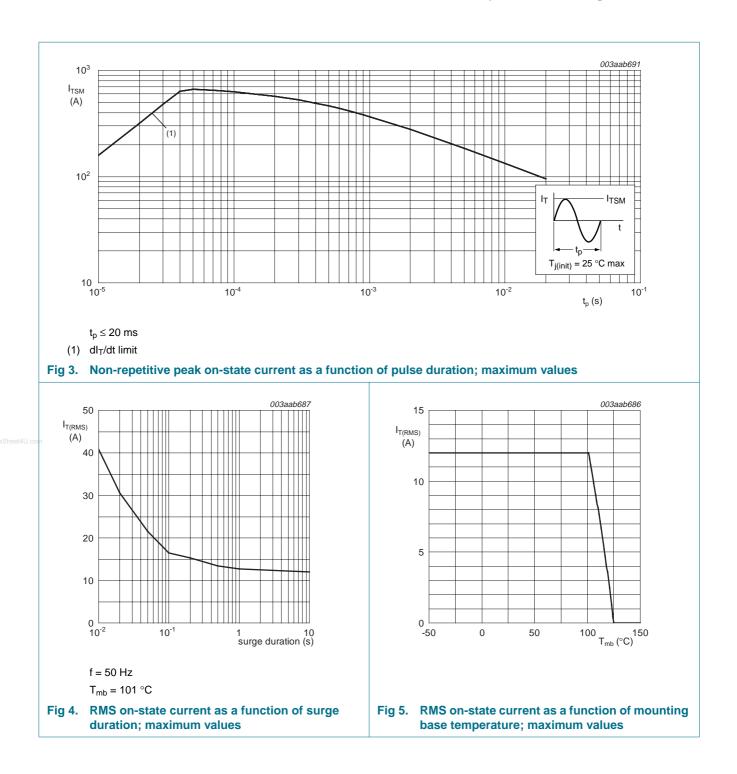
# BTA312B series B and C

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# BTA312B series B and C

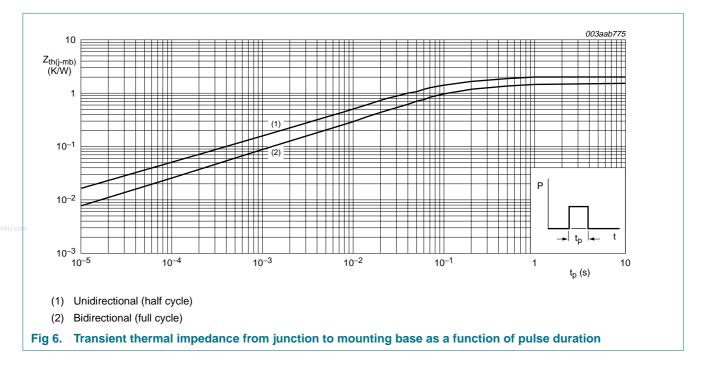
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## 5. Thermal characteristics

Table 4.	Thermal characteristics						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	half cycle; see Figure 6	-	-	2.0	K/W	
		full cycle; see Figure 6	-	-	1.5	K/W	
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	mounted on a printed circuit board; minimum footprint	-	55	-	K/W	



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# 6. Static characteristics

### Table 5. Static characteristics

 $T_i = 25 \circ C$  unless otherwise specified.

Symbol	Parameter	Conditions		BTA312B-600B BTA312B-800B			BTA312B-600C BTA312B-800C		
			Min	Тур	Max	Min	Тур	Max	
I <sub>GT</sub>	gate trigger	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ see } \underline{\text{Figure 8}}$							
	current	T2+ G+	2	-	50	2	-	35	mA
		T2+ G-	2	-	50	2	-	35	mA
		T2- G-	2	-	50	2	-	35	mA
۱L	latching current	$V_D = 12 \text{ V}; \text{ I}_{GT} = 0.1 \text{ A}; \text{ see } \frac{\text{Figure } 10}{100000000000000000000000000000000$							
		T2+ G+	-	-	60	-	-	50	mA
		T2+ G-	-	-	90	-	-	60	mA
		T2– G–	-	-	60	-	-	50	mA
I <sub>H</sub>	holding current	$V_D = 12 \text{ V}; \text{ I}_{GT} = 0.1 \text{ A}; \text{ see } \frac{\text{Figure } 11}{100000000000000000000000000000000$	-	-	60	-	-	35	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 15 A; see <u>Figure 9</u>	-	1.3	1.6	-	1.3	1.6	V
V <sub>GT</sub>	gate trigger	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ see } \frac{\text{Figure 7}}{100000000000000000000000000000000000$	-	0.8	1.5	-	0.8	1.5	V
	voltage	$V_D$ = 400 V; $I_T$ = 0.1 A; $T_j$ = 125 °C	0.25	0.4	-	0.25	0.4	-	V
I <sub>D</sub>	off-state current	$V_D = V_{DRM(max)}; T_j = 125 \ ^{\circ}C$	-	0.1	0.5	-	0.1	0.5	mA

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Max

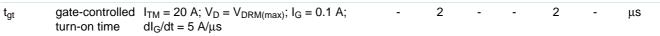
Unit

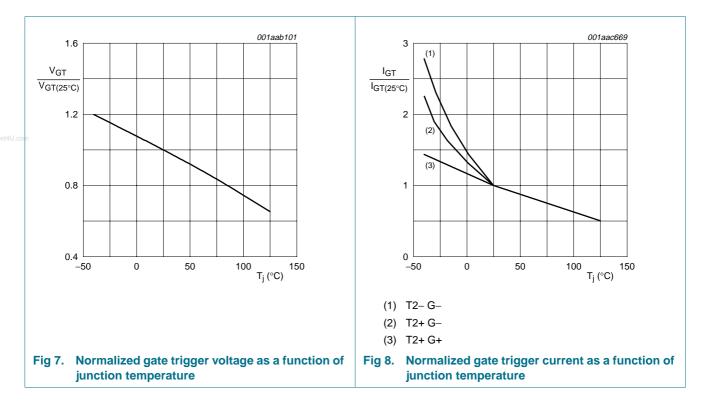
V/µs

A/ms

#### **Dynamic characteristics** 7.

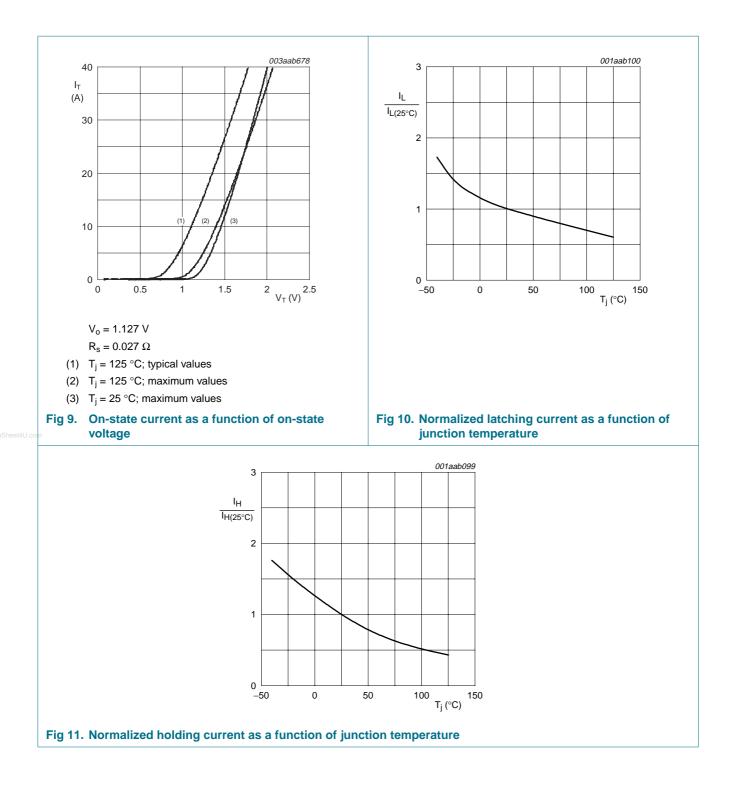
Table 6.	Dynamic cha	racteristics						
Symbol	Parameter	Conditions	BTA312B-600B BTA312B-800B			BTA312B-600C BTA312B-800C		
			Min	Тур	Max	Min	Тур	Max
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM} = 0.67 \times V_{DRM(max)}$ ; $T_j = 125 \text{ °C}$ ; exponential waveform; gate open circuit	1000	2000	-	500	-	-
dl <sub>com</sub> /dt	rate of change of commutating current	$V_{DM}$ = 400 V; T <sub>j</sub> = 125 °C; I <sub>T(RMS)</sub> = 12 A; without snubber; gate open circuit	30	-	-	20	-	-





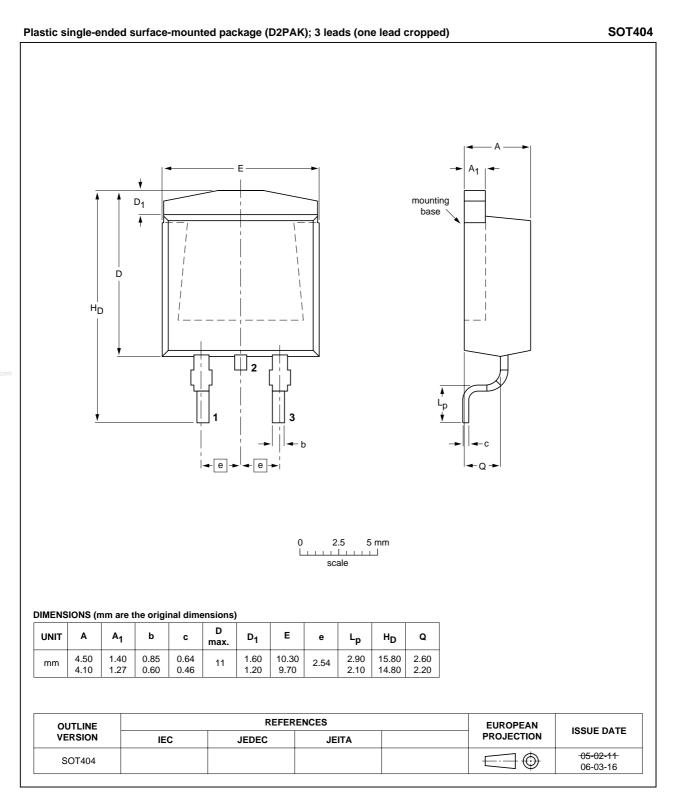
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## 8. Package outline



### Fig 12. Package outline SOT404 (D2PAK)

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# 9. Revision history

Table 7. Revision hist	Revision history						
Document ID	Release date	Data sheet status	Change notice	Supersedes			
BTA312B_SER_B_C_1	20070412	Product data sheet	-	-			

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### **10.1** Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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